

2N5195

Low voltage PNP power transistor

Features

- Low saturation voltage
- PNP transistor

Application

■ Audio, power linear and switching equipment

Description

The device is manufactured in planar technology with "base island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The NPN type is the 2N5192.

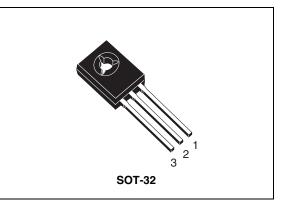
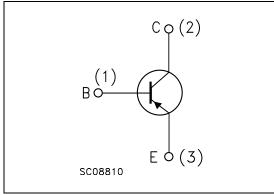


Figure 1. Internal schematic diagram



| Table 1 | 1. | Devices | summary |
|---------|----|---------|---------|
|---------|----|---------|---------|

| Order code | Marking | Package | Packaging |
|------------|---------|---------|-----------|
| 2N5195 | 2N5195 | SOT-32 | Tube |

Doc ID 5074 Rev 4

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1 Electrical ratings

| Table O | |
|----------|--------------------------|
| Table 2. | Absolute maximum ratings |

| Symbol | Parameter | Value | Unit | | | |
|------------------|--|------------|------|--|--|--|
| V _{CBO} | Collector-base voltage ($I_E = 0$) | -80 | V | | | |
| V _{CEO} | Collector-emitter voltage (I _B = 0) | -80 | V | | | |
| V_{EBO} | Emitter-base voltage (I _C = 0) | -5 | V | | | |
| Ι _C | Collector current | -4 | А | | | |
| I _{CM} | Collector peak current | -7 | А | | | |
| Ι _Β | Base current | -1 | А | | | |
| P _{TOT} | Total dissipation at T _{case} = 25 °C | 40 | W | | | |
| T _{STG} | Storage temperature | -65 to 150 | °C | | | |
| Τ _J | Max. operating junction temperature | 150 | °C | | | |

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
|-------------------|---|-------|------|
| R _{thJC} | Thermal resistance junction-case Max | 3.12 | °C/W |
| R _{thJA} | Thermal resistance junction-ambient Max | 100 | °C/W |



2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|--------------------------------------|---|---|---------|---|--------------|----------|
| I _{CBO} | Collector cut-off current (I _E = 0) | V _{CB} = 80 V | | ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,, | -0.1 | mA |
| I _{CEX} | Collector cut-off current (V _{BE} = - 1.5 V) | $V_{CE} = 80 V$ $V_{CE} = 80 V$ $T_{c} = 125 °C$ | | | -0.1 -2 | mA mA |
| I _{CEO} | Collector cut-off current $(I_B = 0)$ | V _{CE} = 80 V | | | -1 | mA |
| I _{EBO} | Emitter cut-off current $(I_{\rm C} = 0)$ | V _{EB} = - 5 V | | | -1 | mA |
| V _{CEO(sus)} ⁽¹⁾ | Collector-emitter sustaining voltage (I _B = 0) | I _C = - 100 mA | -80 | | | v |
| V _{CE(sat)} ⁽¹⁾ | Collector-emitter saturation voltage | $I_{C} = -1.5 A$ $I_{B} = -0.15 A$ $I_{C} = -4 A$ $I_{B} = -1 A$ | | | -0.6 -1.2 | V V |
| V _{BE(on)} ⁽¹⁾ | Base-emitter on voltage | I _C = - 1.5 A V _{CE} = - 2 V | | | -1.2 | V |
| h _{FE} | DC current gain | $ I_{C} = -1.5 \text{ A} \qquad V_{CE} = -2 \text{ V} \\ I_{C} = -4 \text{ A} \qquad V_{CE} = -2 \text{ V} $ | 20 7 | | 80 | |
| f _T | Transition frequency | I _C = - 1 A V _{CE} = - 10 V | 2 | | | MHz |

Table 4.Electrical characteristics

1. Pulse test: pulse duration \leq 300 µs, duty cycle \leq 2 %

2.1 Electrical characteristic (curves)

 $T_J = -40^{\circ}C$

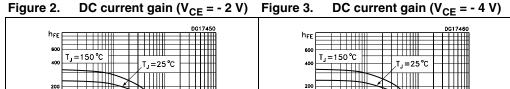
V_{CE} =-2V

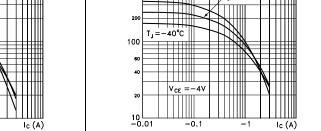
-0.1

100

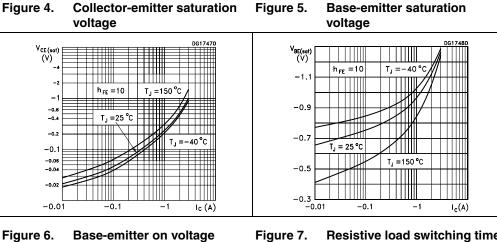
60 40

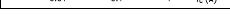
²⁰ 10 -0.01

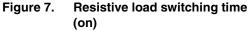


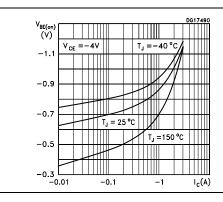






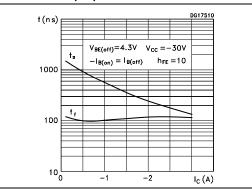






DG17500 t (n s) $V_{BE(off)}=4.3V$ $V_{CC}=-30V$ $-|_{B(on)} = |_{B(off)}$ h_{FE} =10 1000 t, 100 t d 10 └─ 0 -1 -2 $I_{c}(A)$

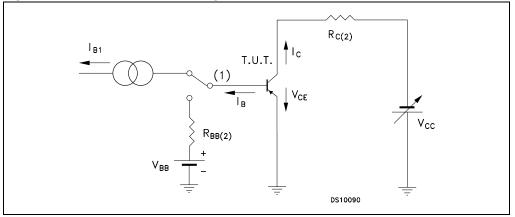
Figure 8. **Resistive load switching time** (off)





2.2 Test circuit

Figure 9. Resistive load switching test circuit



1. Fast electronic switch

2. Non-inductive resistor

3 Package mechanical data

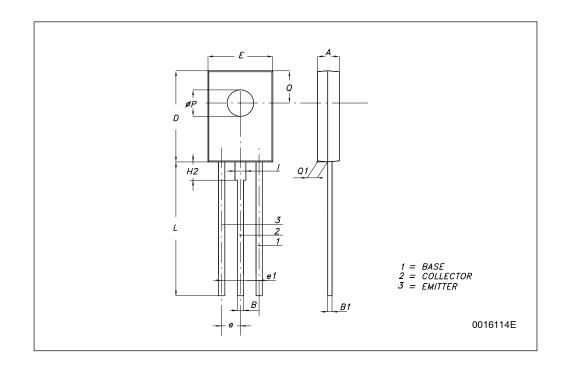
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| эм. | | mm. | |
|-----|------|------|-------|
| | MIN. | ТҮР | MAX. |
| A | 2.4 | | 2.9 |
| В | 0.64 | | 0.88 |
| B1 | 0.39 | | 0.63 |
| D | 10.5 | | 11.05 |
| E | 7.4 | | 7.8 |
| е | 2.04 | 2.29 | 2.54 |
| e1 | 4.07 | 4.58 | 5.08 |
| L | 15.3 | | 16 |
| P | 2.9 | | 3.2 |
| Q | | 3.8 | |
| Q1 | 1 | | 1.52 |
| H2 | | 2.15 | |
| 1 | | 1.27 | |

SOT-32 (TO-126) MECHANICAL DATA





4 Revision history

Table 5.Document revision history

| Date | Revision | Changes |
|-------------|----------|---|
| 21-Jun-2004 | 3 | Document migration, no content change. |
| 02-Nov-2009 | 4 | Updated SOT-32 package mechanical data. |



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